

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

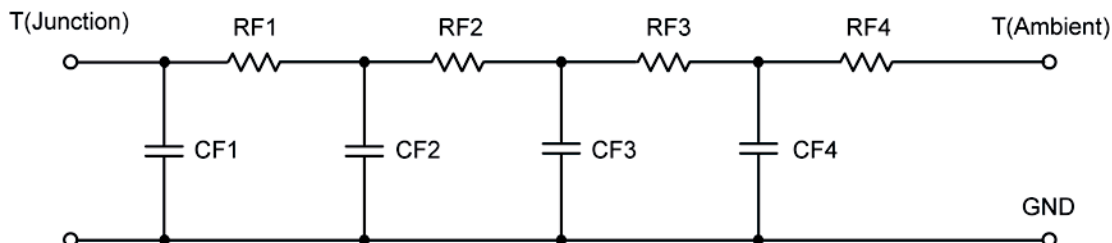
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|--|----------------|------|----------------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 56.6299 | N/A | 16.3442 |
| RT2 | 9.6987 | N/A | 5.8412 |
| RT3 | 27.5497 | N/A | 6.1172 |
| RT4 | 30.7656 | N/A | 16.6502 |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 1.2585 | N/A | 1.4474 m |
| CT2 | 292.8755 μ | N/A | 165.7211 μ |
| CT3 | 28.8786 m | N/A | 159.1680 m |
| CT4 | 2.4901 m | N/A | 4.0724 m |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance (°C/W) | | | |
|---------------------------------|------------|------|------------|
| Junction to | Ambient | Case | Foot |
| RF1 | 11.7482 | N/A | 9.3126 |
| RF2 | 33.4099 | N/A | 21.7163 |
| RF3 | 24.3359 | N/A | 8.4387 |
| RF4 | 55.0458 | N/A | 5.5442 |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 264.9457 u | N/A | 170.4864 u |
| CF2 | 1.9901 m | N/A | 1.1574 m |
| CF3 | 29.4999 m | N/A | 1.9990 m |
| CF4 | 1.2617 | N/A | 191.7478 m |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

